## NSN 5961-01-072-5029

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View Online at https://aerobasegroup.com/nsn/5961-01-072-5029 **Overall Length:** 0.175 inches **Overall Diameter:** 0.200 inches **Internal Configuration:** Junction contact **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector to emitter, sustained and 7.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 100.00 microamperes source cutoff current **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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